

Comment on “Theory of Spin Hall Effect: Extension of the Drude Model”

V. Ya. Kravchenko

Institute of Solid State Physics, Russian Academy of Sciences, Chernogolovka, 142432 Moscow District, Russia

E. M. Chudnovsky has recently posted on the ArXive his Reply [1] to my Comment [2] on his recent Letter [3]. In order to avoid possible misunderstandings in the evaluation of his Letter, I am posting my Comment with some remarks on the contents of his Reply.

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The Letter “Theory of Spin Hall Effect: Extension of the Drude model” [3] is related to a subject that has been widely discussed during the last few years (for a review, see Ref.[4]). A simple physical model of the spin Hall (SH) effect is proposed that allegedly allows evaluating its magnitude. In order to determine the SH component of the current driven in a metal or semiconductor by an electric field, the Author includes in the single-electronic Hamiltonian the relativistic expression of spin-orbit interaction in its conventional form, which contains ∇U , the gradient of the electron’s potential energy U . According to Eq.(2) and the explanatory text in Ref.[3], the Author ignores U , without any justification, the Hartree potential created by free electrons system maintaining electrical neutrality. This omission is crucial for the final result. After some manipulations with $\hat{p}$ - and $\hat{r}$ -operators, the Author proceeds with the Drude-like semiclassical equations for electron motion, *i.e.*, the Drude equation (11), where $-\nabla U$ is playing the role of a non-relativistic force and $\partial^2 U / \partial r_i \partial r_j$ — the role of spin-orbit force (see Eqs. (8), (11), and (14) in Ref.[3]). Later in the text, a very simplified situation is considered, with all conventional mechanisms of SH effect (“intrinsic”, related to the symmetry properties of the spin-orbit part of the dispersion law, and “extrinsic”, caused by the asymmetry of impurity scattering [4]) disregarded. Therefore, the SH effect proposed in Ref.[3] is supposed to be of a new type.

However, the results of the Author’s calculations are incorrect.

According to Eqs. (15), (22), and (25) in Ref.[3], the

SH conductivity σ_s is proportional to $\langle \partial^2 \Phi_0 / \partial r_i \partial r_j \rangle = \delta_{ij} \nabla^2 \Phi_0 / 3$. Here Φ_0 is the *total* electrostatic potential in a perfect crystal (see Eq. (2) in Ref.[3]). Therefore, it must be equal to the sum of the potentials created by the lattice and the Hartree potential of free electrons. According to the Poisson equation, $\nabla^2 \Phi_0$ is proportional to the *total* electric charge density. For this charge density, the Author uses *the density of the ion charge only*. Clearly, this is incorrect. In conductors, electrons move in the self-consistent field of ions and the electron reservoir. The standard method of accounting for electron-electron interaction is insuring the electrical neutrality. In conductors, in the framework of a semiclassical approach, the condition of the neutrality is fulfilled. Therefore, the total charge density in Eqs. (22) and (26) is equal to zero, and SH conductivity σ_s (see Eq.(22), (28) in Ref.[1]) vanishes.

In the Author’s Reply [1], there is no justification of the complete violation of the electroneutrality condition in the considered physical situation, in the framework of the single-electron semiclassical approach. The Author actually does not respond to my criticism regarding his zero-result and simply repeats the content of his paper [3].

In conclusion, traditional mechanisms of SH effect rely on the strong microscopic electric fields in a close vicinity of nuclei. The “new” effect is ascribed to an ultrastrong smooth electric field developing at the sample scale. However, because of the electric neutrality, this field vanishes. The procedure of Ref.[3] results in zero spin Hall effect, contrary to the Authors assertion.

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 - [2] V. Ya. Kravchenko, Phys. Rev. Lett. **100**, 199703 (2008)
 - [3] E. M. Chudnovsky, Phys. Rev. Lett. **99**, 206601 (2007).
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of Magnetism in Advanced Magnetic Materials, vol.5. Eds. H. Kronmuller and S. Parkin, Wiley-Interscience, 2007 (see arXiv:cond-mat/0603306v3).